

Device Modeling Report

COMPONENTS: Power MOSFET (Professional)
PART NUMBER: SSM3K101TU
MANUFACTURER: TOSHIBA
Body Diode (Professional) / ESD Protection Diode



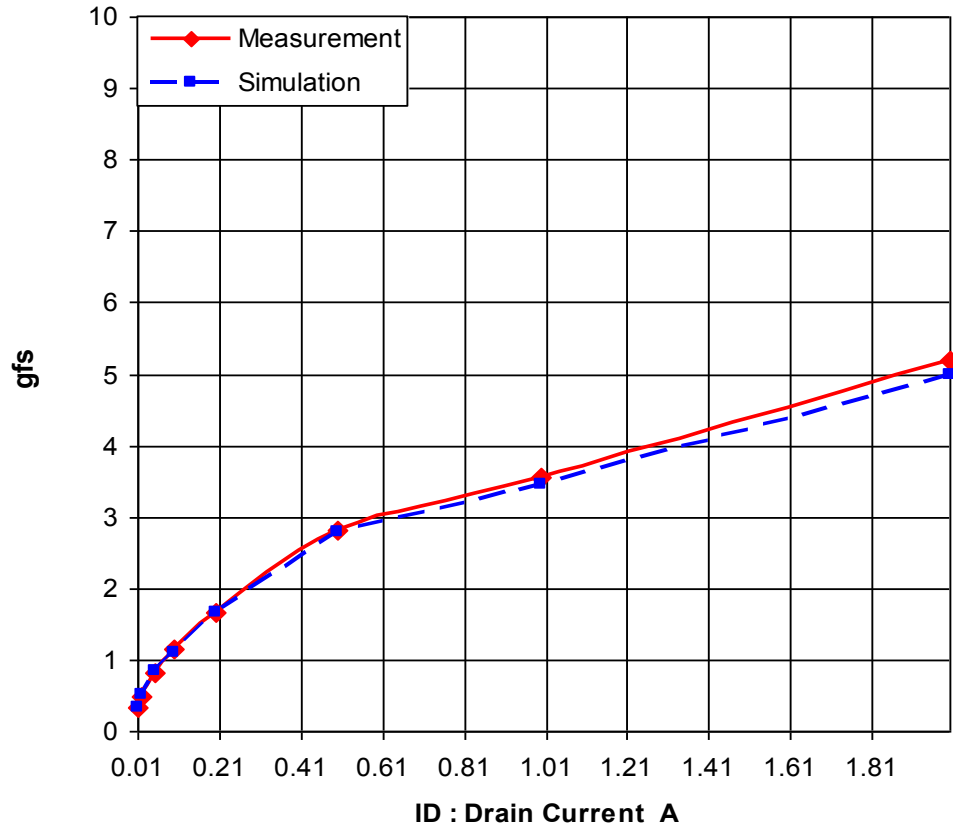
Bee Technologies Inc.

MOSFET MODEL

Pspice model parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Modility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristic

Circuit Simulation Result

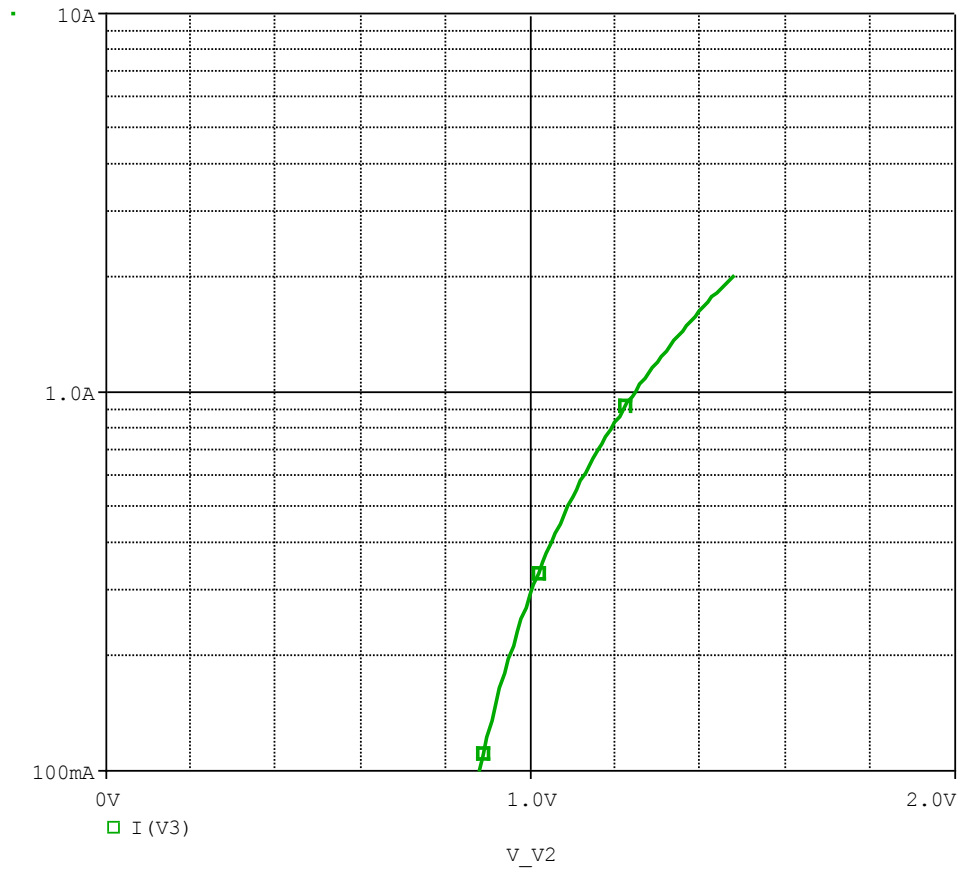


Comparison table

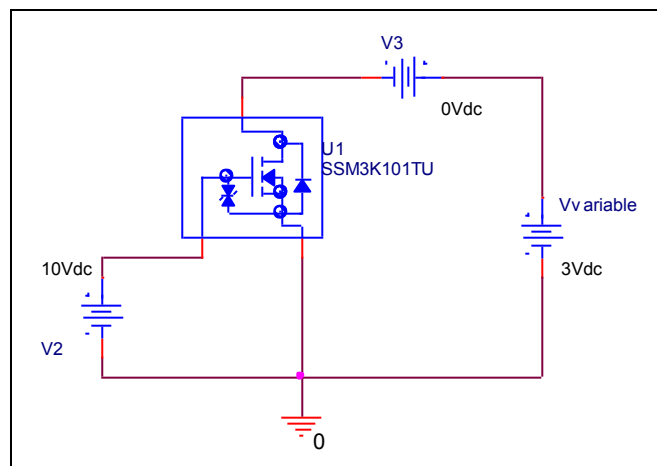
Id(A)	gfs		Error(%)
	Measurement	Simulation	
0.010	0.327	0.333	1.835
0.020	0.491	0.500	1.833
0.050	0.814	0.833	2.334
0.100	1.140	1.111	-2.544
0.200	1.667	1.667	0.000
0.500	2.825	2.778	-1.664
1.000	3.567	3.448	-3.336
2.000	5.200	5.000	-3.846

V_{gs}-I_d Characteristic

Circuit Simulation result

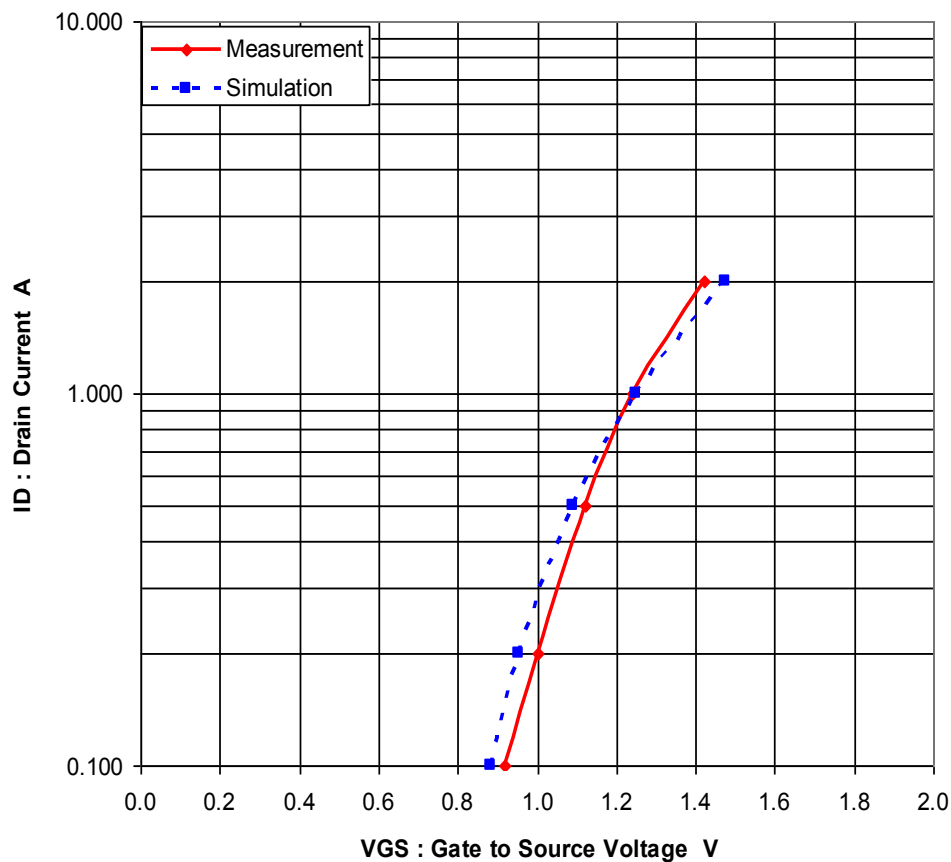


Evaluation circuit



Comparison Graph

Circuit Simulation Result

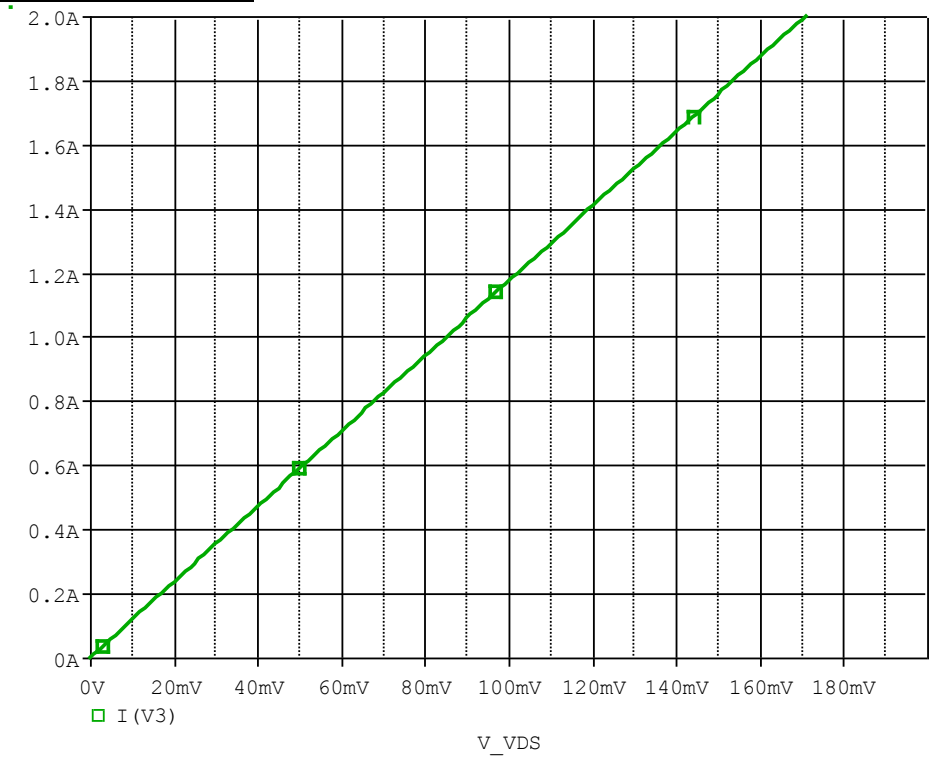


Simulation Result

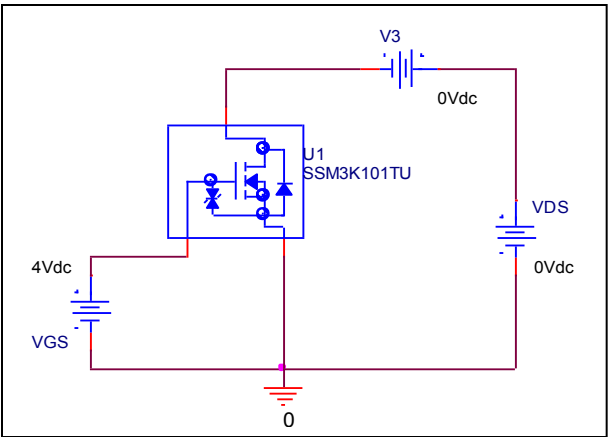
I_D (A)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
0.100	0.920	0.882	-4.130
0.200	1.000	0.952	-4.800
0.500	1.120	1.091	-2.589
1.000	1.240	1.248	0.645
2.000	1.420	1.476	3.944

Rds(on) Characteristic

Circuit Simulation result



Evaluation circuit

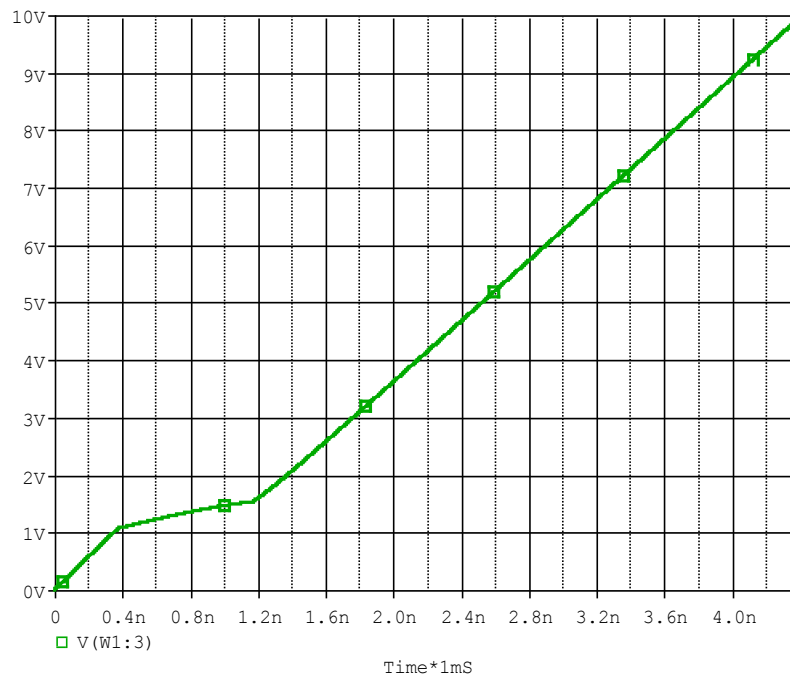


Simulation Result

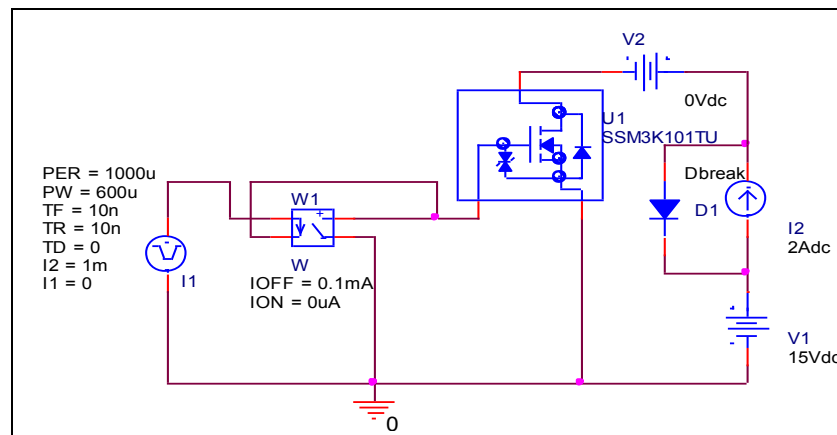
$I_D=1A, V_{GS}=4V$	Measurement	Simulation	Error (%)
$R_{DS(on)}$ (Ω)	85.000	85.085	0.100

Gate Charge Characteristic

Circuit Simulation result

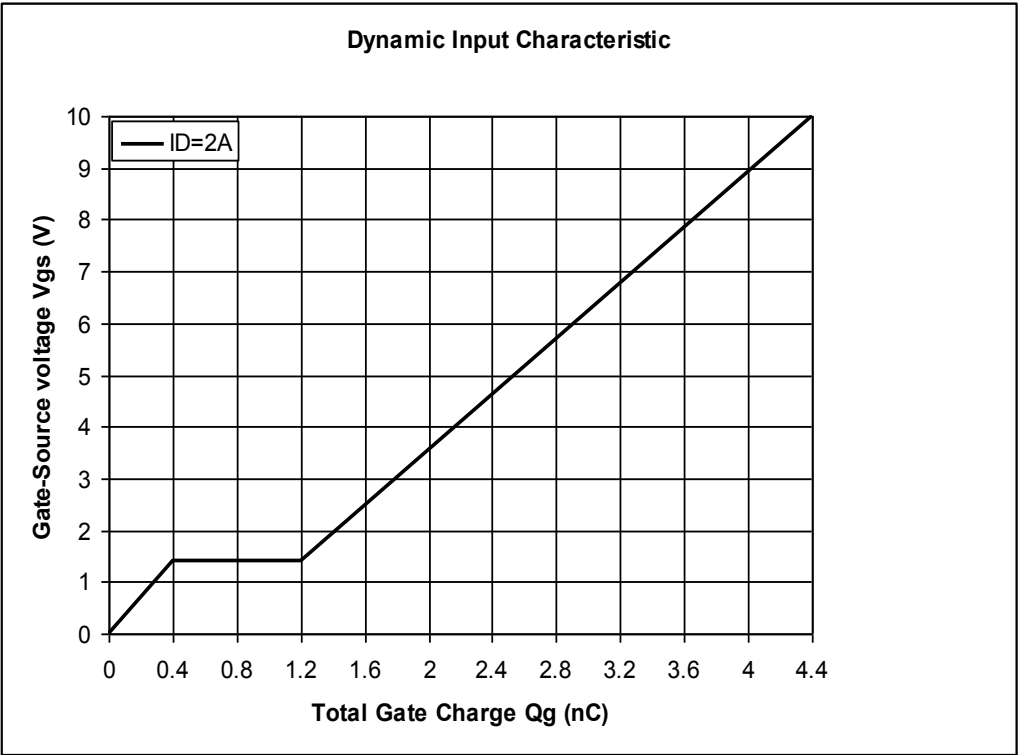


Evaluation circuit

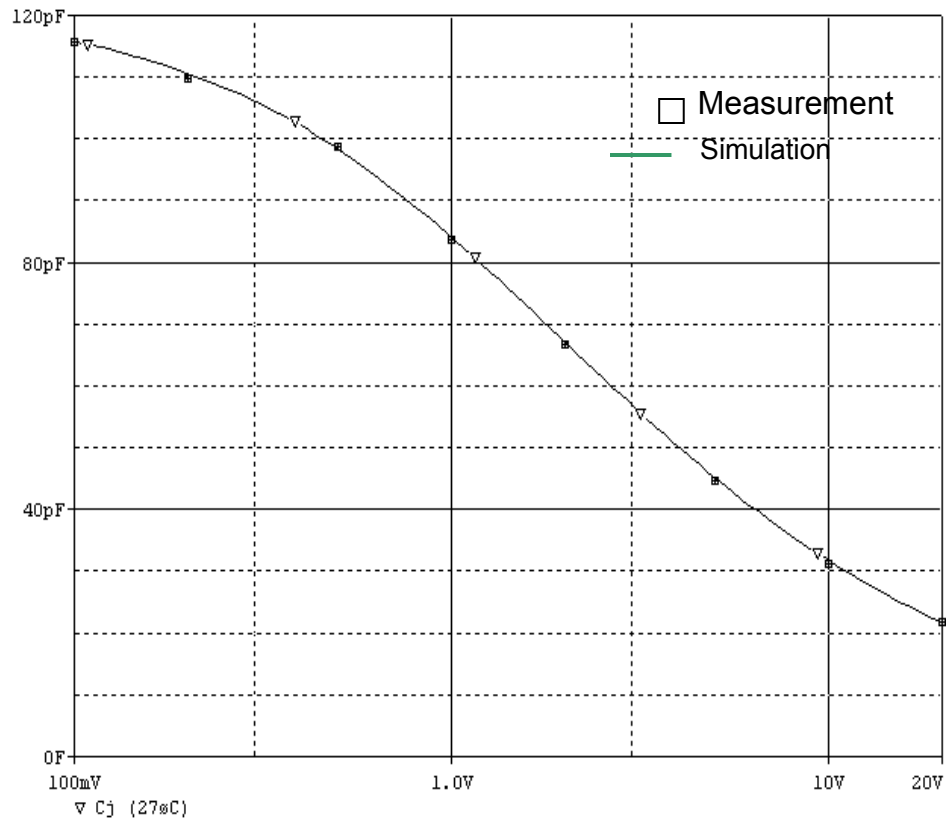


Simulation Result

$V_{DD}=15V, I_D=2A$ $V_{GS}=10V$	Measurement	Simulation	Error (%)
Qgs(nc)	0.400	0.401	0.250
Qgd(nc)	0.800	0.801	0.125
Qg(nc)	4.400	4.402	0.045



Capacitance Characteristic

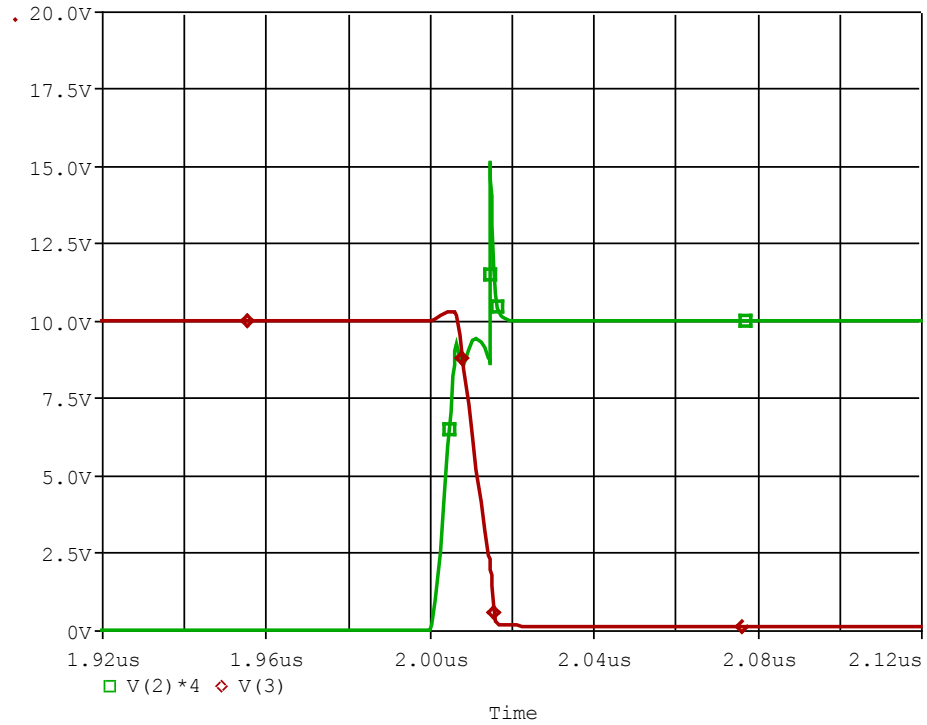


Simulation Result

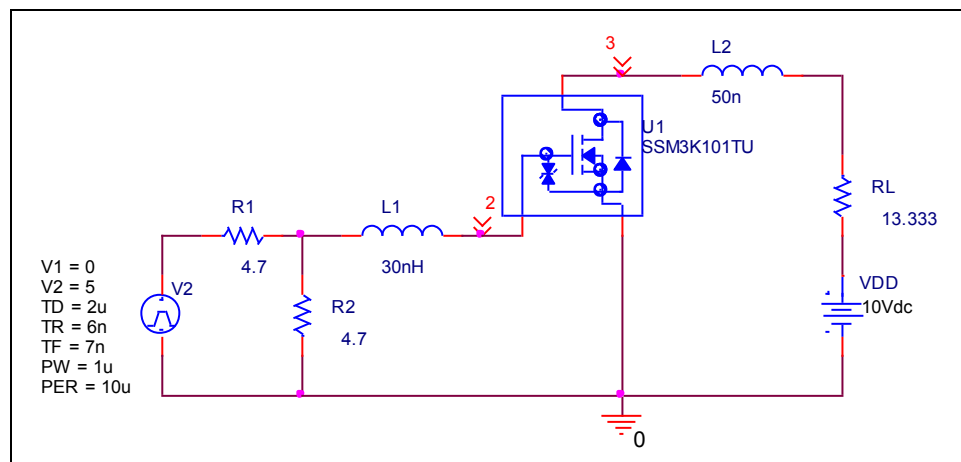
$V_{DS}(V)$	Cbd(pF)		Error(%)
	Measurement	Simulation	
0.100	116.000	115.750	-0.216
0.200	110.000	110.650	0.591
0.500	99.000	98.300	-0.707
1.000	84.000	84.100	0.119
2.000	67.000	67.200	0.299
5.000	45.000	45.100	0.222
10.000	31.500	31.900	1.270
20.000	22.000	21.670	-1.500

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

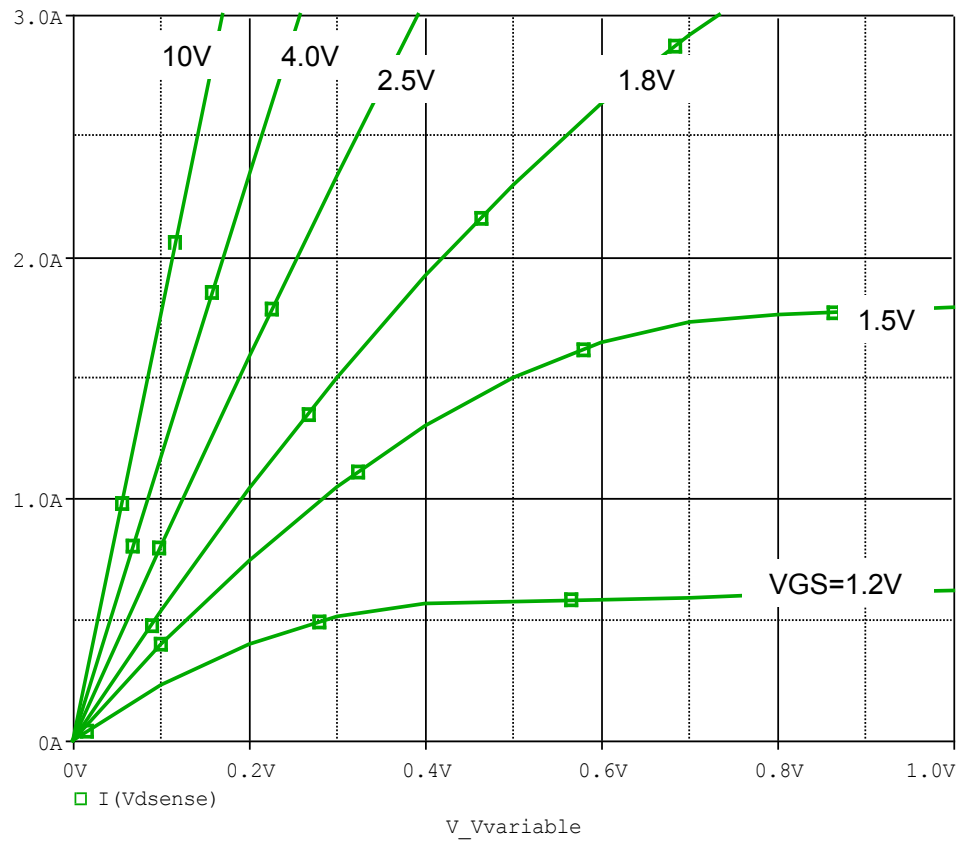


Simulation Result

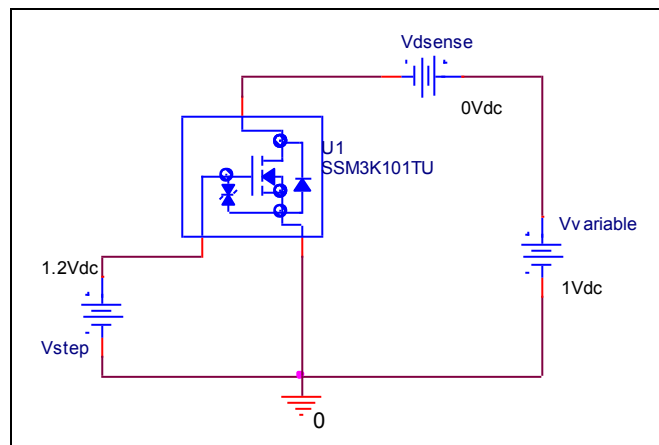
$I_D=0.75A$, $V_{DD}=10V$ $V_{GS}=2.5V$	Measurement	Simulation	Error(%)
Ton(ns)	14.000	14.002	0.014

Output Characteristic

Circuit Simulation result

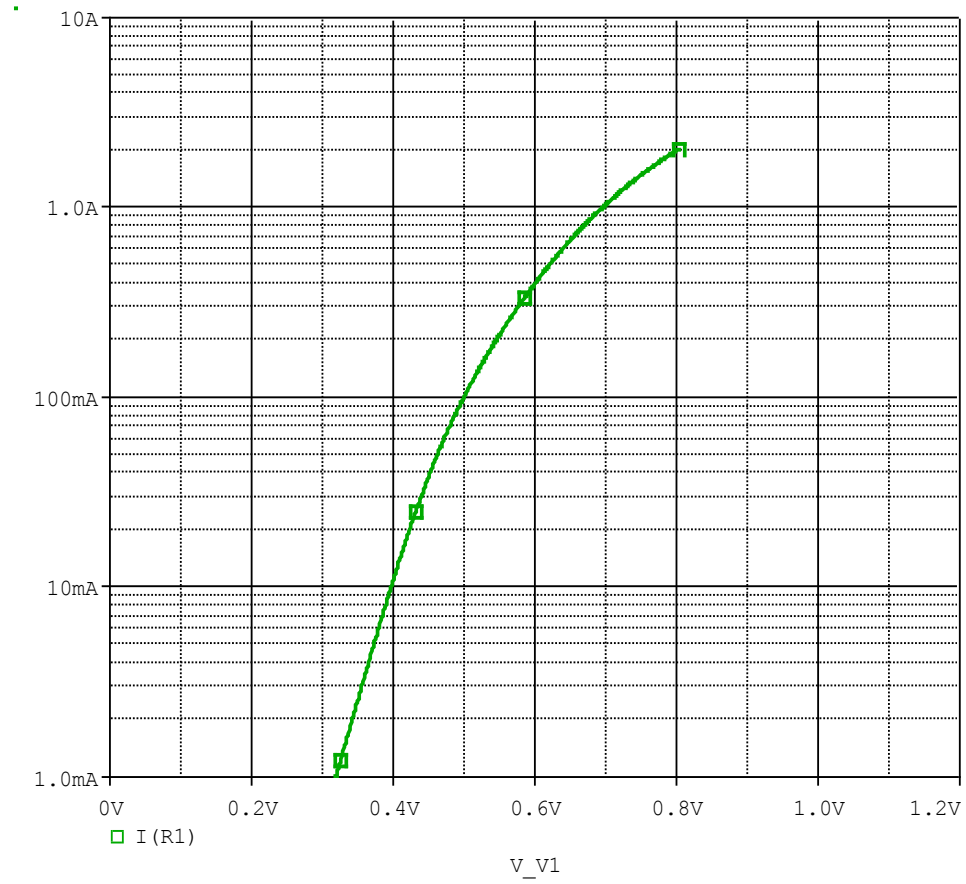


Evaluation circuit

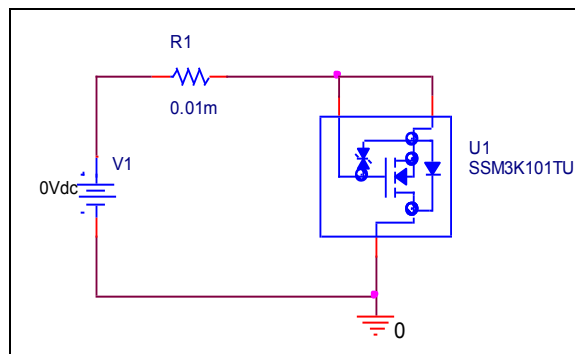


Forward Current Characteristic

Circuit Simulation Result

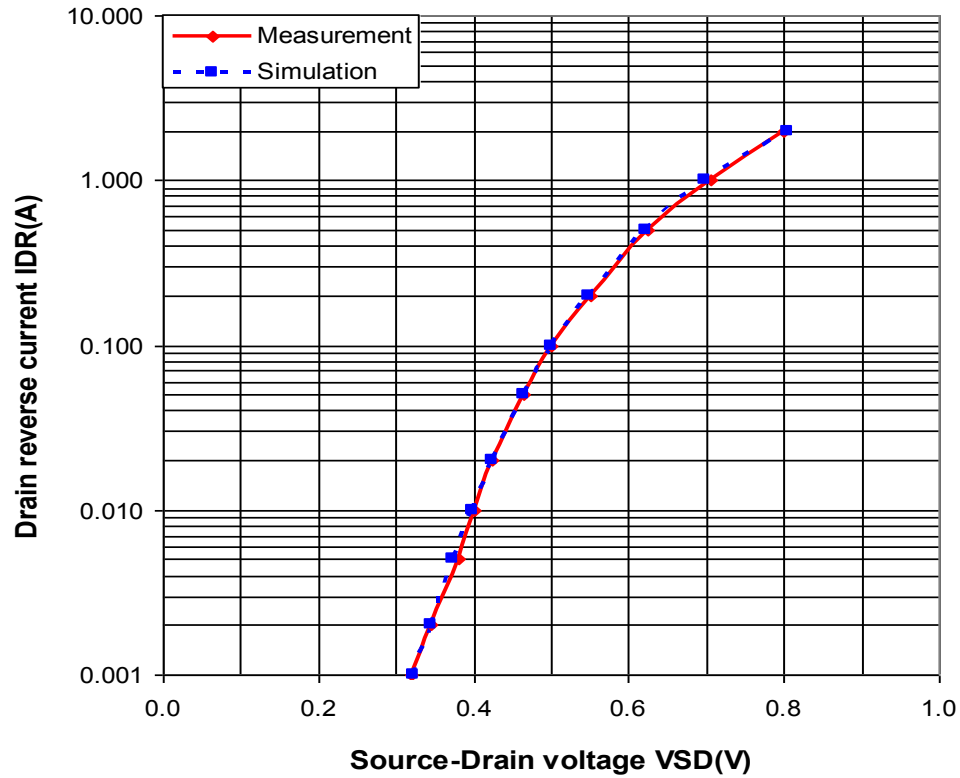


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

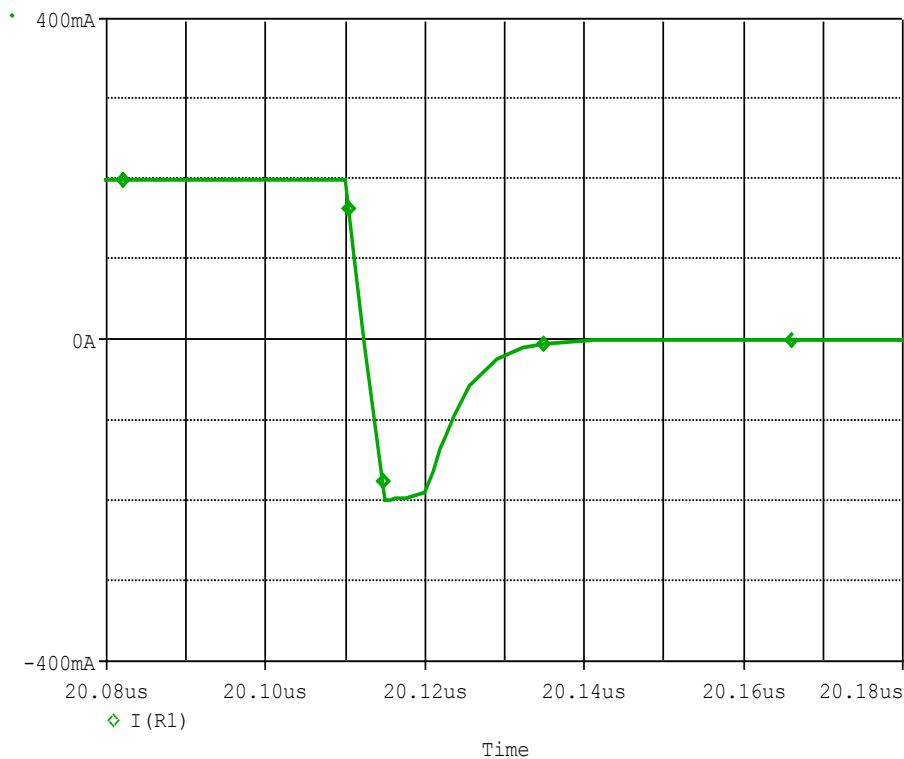


Simulation Result

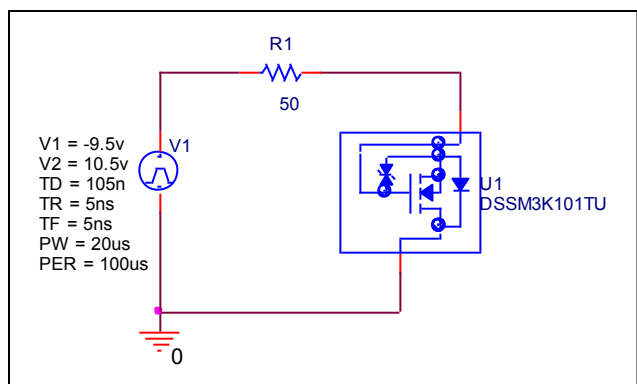
$IDR(A)$	$VSD(V)$ Measurement	$VSD(V)$ Simulation	%Error
0.001	0.320	0.322	0.625
0.002	0.345	0.344	-0.290
0.005	0.380	0.374	-1.579
0.010	0.400	0.399	-0.250
0.020	0.425	0.424	-0.235
0.050	0.465	0.464	-0.215
0.100	0.500	0.501	0.200
0.200	0.550	0.547	-0.545
0.500	0.625	0.623	-0.320
1.000	0.705	0.698	-0.993
2.000	0.800	0.804	0.500

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

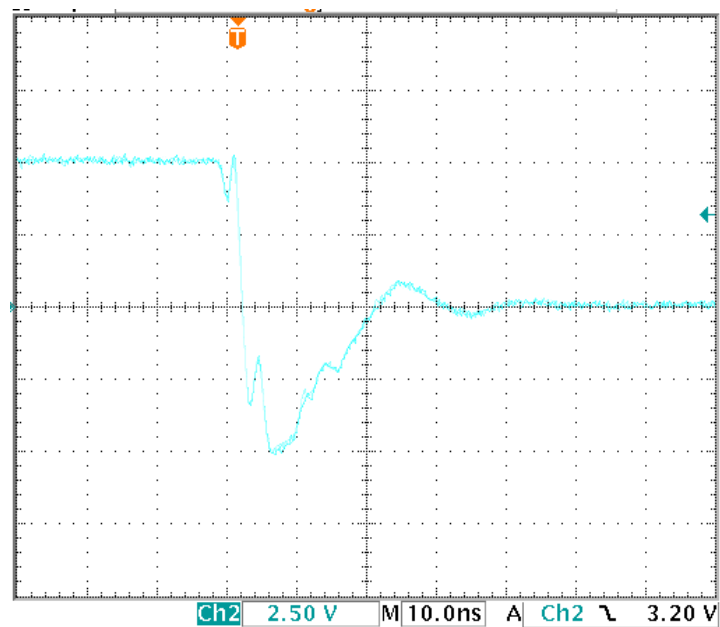


Compare Measurement vs. Simulation

	Measurement	Simulation	Error (%)
Trj(ns)	7.200	7.220	0.278
trb(ns)	10.200	10.270	0.686
trr(ns)	17.400	17.490	0.517

Reverse Recovery Characteristic

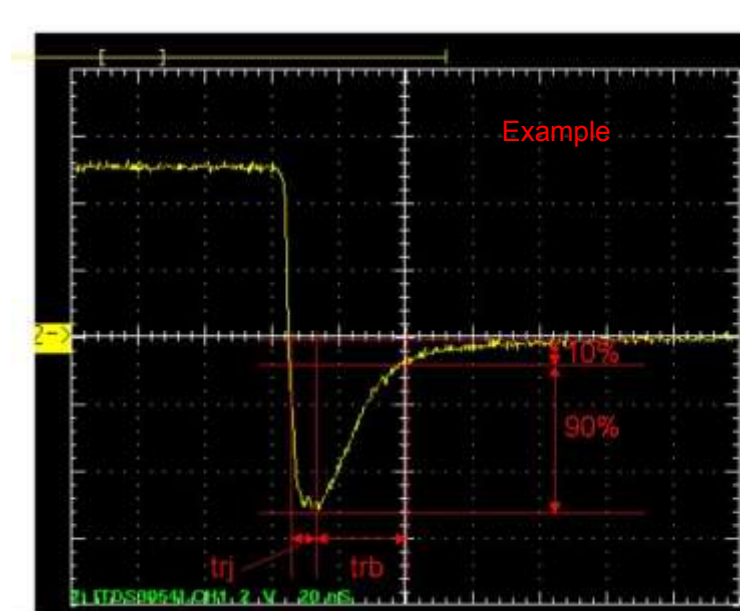
Reference



$T_{rj}=7.2(\text{ns})$

$T_{rb}=10.2(\text{ns})$

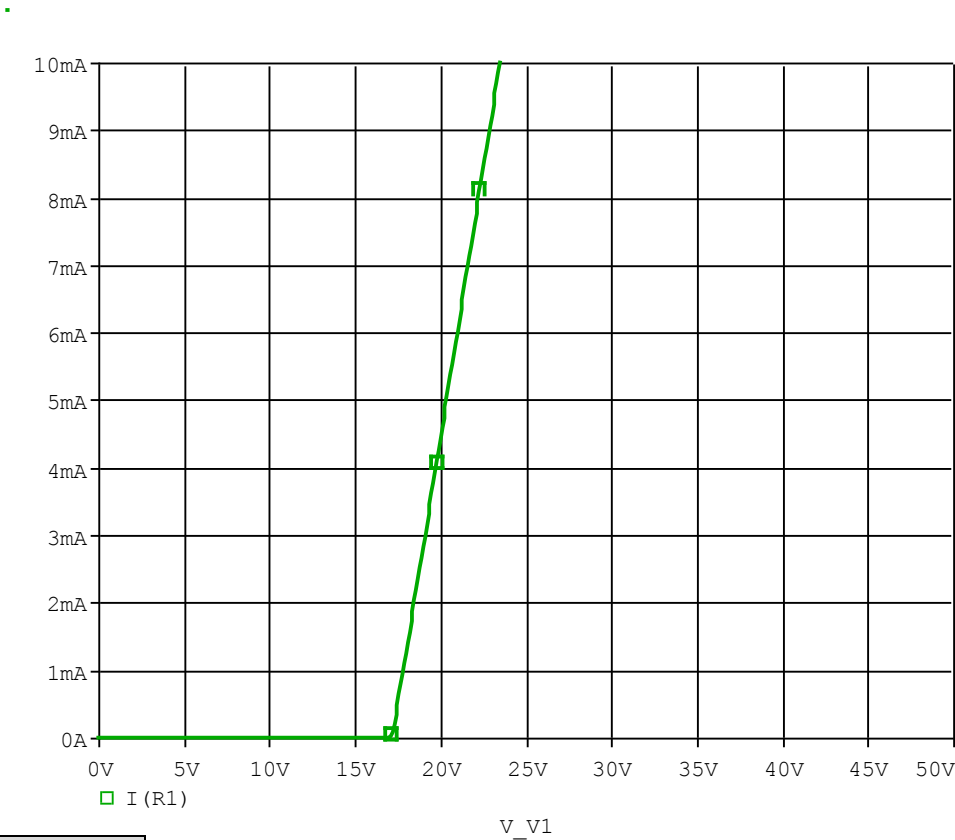
Conditions: $I_{fwd}=I_{rev}=0.2(\text{A})$, $R_I=50$



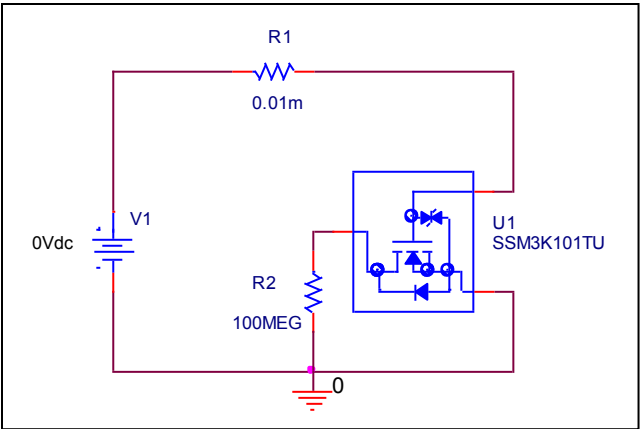
Relation between t_{rj} and t_{rb}

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

